A Monolithic MQW InP/InGaAsP-Based Comb Generator

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Abstract — We report a monolithic optical frequency comb generator using quaternary/quaternary multiple quantum well InP/InGaAsP material as phase modulator and gain medium in a Frequency Modulated (FM) laser design. The modulation was generated by quantum confined Stark effect to achieve a comb-line spacing of 24.4 GHz. The laser was fabricated using a single epitaxial growth step and quantum well intermixing to realize low loss phase and modulation sections. The resulting comb generator produces lines with a spacing exactly given by the modulation frequency, differential phase noise between adjacent lines of -82 dBc/Hz at 1 kHz offset and a comb spectrum width of up to 2 THz.

Index Terms — Optical frequency comb generation, Laser diode, FM laser.

I. INTRODUCTION

Many different applications, ranging from Dense WDM optical communications, to photonic THz synthesis require a reliable and cost effective frequency reference source. Atomic or molecular resonances are commonly used to provide absolute frequency references, however they are limited to a few particular frequencies [1]. To overcome such limitation several other solutions have been proposed to provide a regular spaced frequency comb, such as a Fabry-Perot interferometer or a fibre ring resonator [2]. Unfortunately the frequency accuracy and stability of these devices are limited by the optical length of the resonators. Another solution is the use of deep angle modulation of an optical source to generate precisely spaced frequency lines [3]. However the power and number of frequency lines and their spacing are limited by the difficulty of realising such modulation at high frequency. Other solutions such as an amplified fibre loop comb generator [4] or mode locked semiconductor lasers [5] can offer hundreds of lines with a spacing from 10 to 25 GHz over a band of at least 1THz with a stability limited by the thermal stability of the semiconductor laser (master laser in the case of the fibre loop).

II. PRINCIPLE OF THE FM SOURCE

As stated above FM operation laser occurs when a laser cavity phase is modulated at a frequency close to the axial frequency [6]. At this point of operation, one will observe a continuous wave (CW) output as there is no amplitude modulation and the spectrum will comprise a number of lines depending on the frequency detuning from the axial mode and the amplitude of the modulation. When the modulation frequency is equal to the axial frequency the laser will transfer to a mode-locked pulse regime [6]. The FM laser regime is generated by the phase modulation which induces coupling between the different modes of the cavity. The resulting spectrum can be described by the following equations:

\[ E(t) = E_0 \sum_{n=-\infty}^{\infty} J_n(\Gamma) e^{j(\omega_0 + n\omega_m)t} \]  

(1).

\[ \Gamma = \frac{\Delta \Phi}{2\pi} \frac{\omega_{ax}}{|\omega_{ax} - \omega_m|} \]  

(2).
In these equations $E_0$ is the amplitude of the optical field, $\omega_0$ is the laser operating frequency, $\omega_m$ is the modulation frequency, $\omega_{ax}$ is the axial mode spacing of the Fabry-Perot cavity, $\Delta \Phi$ is the amplitude of the phase modulation and $J_n$ is an ordinary Bessel function. Note that these equations represent an ideal laser with a flat gain spectrum and pure single mode operation. A long cavity semiconductor laser will typically be multimode and absorb more light at the short wavelength end of the spectrum, thus affecting the resulting spectrum. The perfect theoretical laser will generate a spectrum as shown in Fig 1.

![Fig. 1. Theoretical spectrum of an FM laser.](image)

### III. DESCRIPTION OF THE LASER

Fig 2 (left) shows a schematic of the three section laser. The laser was 1.85 mm long (~25 GHz axial mode spacing) with 70 µm long modulation and phase sections. The phase section was use to change the axial mode spacing thus the frequency detuning while the modulation frequency could remain constant. Fig 2 (right) shows the epitaxial structure of the material used for the laser. The structure was grown by metal-organic vapour phase epitaxy (MOVPE) on a semi-insulating InP substrate. The active region consists of eight 7nm-wide compressively strained (1%) InGaAsP Q1.65 wells, alternating with seven 14nm-wide tensile strained (0.5%) InGaAsP Q1.3 barriers, sandwiched between two 10nm-thick InGaAsP Q1.3 waveguide layers. On top of the InGaAs contact layer, a 0.5 m InP buffer layer and a final 0.1 m InGaAs buffer layer were grown. They were used to protect the contact cap from damage as shallow ion implantation was used to generate QWI as in [8]. For this work we implanted $8 \times 10^{14}$ P ions at 100 keV energy and 200 °C. With this implantation energy damage was restricted to the buffer layer, thus when it was subsequently removed the surface quality of the contact cap was intact. The wafer was masked with 600 nm of PECVD SiO2 during implantation in order to protect the gain sections. After implantation the wafer was rapidly thermally processed at 650 °C for 90 seconds which created a 35 nm blue-shift of the bandgap in the phase and modulator sections. Part of the wafer was then processed into PIN devices, and photocurrent spectra were measured to extract the spectral dependence of the material absorption as a function of reverse bias. Such a measurement allowed the estimation of the effect of QCSE on refractive index. This showed that the refractive index for the propagating mode will change by 0.03 with 2 V reverse Bias. Such an index change is sufficient to create the desired FM laser effect.

The fabricated laser was a ridge waveguide design with oxide-bridged contacts in order to reduce the capacitance of the modulator section (picture in Fig 2). The different sections were separated by an isolation trench through the highly doped top layers. The oxide-bridged contact for the modulation section allowed a 380 fF measured capacitance and a 20Ω series resistance resulting in a maximum modulation bandwidth of 42 GHz. As both phase section and modulation section were intermixed, the laser threshold remained relatively low at 80 mA for a 1.88mm long device. The laser was operated at 200 mA bias current giving a total output of 1 mW (0.5 mW coupled into a single mode fibre).

### IV. EXPERIMENTS AND RESULTS

Fig 3 shows the different systems used to characterize the FM laser. First the output spectrum of the laser was assessed with a spectrum analyzer. Finer spectral studies were also done with a Fabry-Perot interferometer with a spectral resolution of 10 MHz. The laser output power
stability was also studied using a fast photodetector (50 GHz bandwidth) and a sampling oscilloscope. This allowed intensity modulation effects on the laser output to be studied. The stability of the line spacing and its relation to the frequency source were assessed by heterodyning two adjacent lines and sending the resulting signal to the fast photodetector which was connected to a spectrum analyzer. Note that in this case Filters were used at the output of the erbium doped fibre amplifiers (EDFA) to reduce the amplified spontaneous emission (ASE) level in the resulting spectrum. Fig. 4 shows the output spectrum of the laser with and without 24.4 GHz modulation (2V peak to peak with 2V negative bias). With no modulation lasing was on a single longitudinal mode. With modulation the spectrum shows a large number of lines appearing across the spectrum. When the phase was changed in order to detune the laser axial frequency further from the modulation frequency the number of lines diminished and were closer to the original peak frequency as expected for a FM laser. Note that the spectrum is not symmetric as for the ideal example given previously. This is mainly due to the strong absorption on the short wavelength side of the spectrum. Furthermore, the trenches used to isolate the different sections were inducing small reflection thus creating a system of coupled Fabry-Perot cavities. This induced higher losses in the cavity at frequency spacings determined by the length of the modulation section. This was reflected in the optical spectrum by the lack of lines created in some part of it.

To assess the quality of the created comb lines their linewidth was measured with a Fabry-Perot interferometer with a 10 MHz resolution. The non-modulated laser had a measured linewidth of 14 MHz. When modulated the laser was creating lines with the same measured linewidth.

To confirm that the device was operating as an FM laser the stability of its output power was measured with a fast photodetector both on a spectrum analyzer and on a sampling oscilloscope. As expected there is a slight amplitude modulation as the QCSE slightly changes the absorption of the modulation section. The spectrum analyzer did show a weak peak at 24.4 GHz in agreement with the previous measurement. In order to fully assess the FM operation, the comb line spacing should be measured and its relation to the modulation frequency should be demonstrated. In order to do this final measurement we used the heterodyne system described previously with 0.5 nm wide line filters on each branch of the system.

Fig. 4 shows spectrums with and without modulation.
The result is shown in Figure 6 for one given pair of lines. For this measurement the spectrum analyser span was 100 kHz and the resolution bandwidth was 1 kHz. The line was at the exact frequency of the modulation source and had the same spectral purity as expected. Thus as the comb lines were spaced by the modulation frequency, we could definitely conclude the device was operating as a FM laser. Phase noise measurements were also made on the heterodyne signal to compare it with the frequency source. It showed that no added phase noise was coming from the laser and that the stability of the line spacing was given by the frequency source. Typically the phase noise was -82 dBc/Hz at 1 kHz and -108 dBc/Hz at 1 MHz.

VII. CONCLUSION

We have demonstrated FM operation in a monolithic semiconductor laser. This optical frequency comb-generator offers 24.4 GHz spaced lines over a spectral width of 15 nm (~2THz). The laser lines were exactly spaced by the modulation frequency and the residual intensity modulation was less than 20 %. Each line had the same linewidth of 14 MHz as the non modulated laser. When heterodyned two adjacent line gave a high purity frequency with phase noise limited by the frequency source. This achievement was possible using a combination of different fabrication techniques on the quaternary/quaternary InGaAsP/InP material. First the bandgap of part of the wafer was blue shifted using QWI by shallow ion implant and RTP. The 35 nm bandgap shift obtained allowed low signal absorption in the phase and modulation sections of the device. Secondly the fabrication of the device was made using oxide-bridge techniques to reduce the capacitance of the modulation section to 380 ff. This allowed for an efficient reverse bias modulation using QCSE at 24.4 GHz which was within the bandwidth of the modulation section (42 GHz). Such monolithic comb generators provide a compact alternative to fibre loop techniques with larger comb line output powers than passive phase modulator techniques.

REFERENCES